DS4373-1.2

1200V

100A

112ns

FRD05610012E

FAST RECOVERY EPITAXIAL DIODE CHIP

APPLICATIONS

- Switch Mode Power Supplies.
- Motor Control.
- Free Wheel/Antiparallel Diode For Use With IGBT And Other Power Switches In Inverters And Welding Applications.

CHIP DETAILS

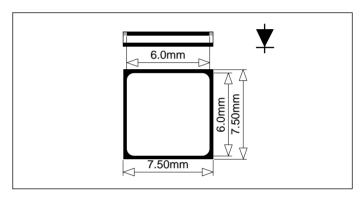
TYPICAL KEY PARAMETERS

FEATURES

■ Planar Structure With "HIVOX" Semi-Insulating Polysilicon Junction Passivation And Soft Recovery Characteristics.

VOLTAGE RATINGS

Type Number	Repetitive Peak Reverse Voltage V	Conditions
FRD05610012E	1200	T _j = 150°C



Typical chip thickness: 465μm.

Wire sizes: $8 \ge$ bondwires $300\mu m \varnothing$.

Composition of wire: 99.999% Aluminium.

Back metal: Aluminium, Titanium, Nickel, Silver.

 T_{max} for chip **NOT** to exceed 275 °C for more than 15 minutes

during soldering, using 96S solder.

Packing for shipment is either membrane or waffle tray.

Static sensitive device - observe static handling precautions.

CURRENT RATING

Symbol	Parameter	Conditions	Max.	Units
I _F	Forward current	-	100	Α

FRD05610012E

THERMAL RATING

Symbol	Parameter	Conditions	Max.	Units	
T _i	Junction temperature	-	150	°C	
T _{stg}	Storage temperature range	-	-55 to +150	°C	

CHARACTERISTICS

Symbol	Parameter	Conditions	Тур.	Max.	Units
V _{FM}	Forward voltage	At I _F = 100A peak, T _j = 25°C	2.25	2.7	V
		At I _F = 100A peak, T _j = 125°C	1.9	2.3	V
I _{RM}	Peak reverse current	At V_{RRM} , $T_j = 125^{\circ}C$	-	1	mA
t _{rr}	Reverse recovery time	$I_F = 100A$, $di_{RR}/dt = 300A/\mu s$	110	-	ns
Q _{RR}	Recovered charge	$T_{j} = 25^{\circ}C, V_{R} = 50\%V_{RRM}$	4	-	μС
t _{rr}	Reverse recovery time	$I_F = 100A$, $di_{RR}/dt = 300A/\mu s$	240	-	ns
Q _{RR}	Recovered charge	$T_j = 125^{\circ}C, V_R = 50\%V_{RRM}$	12	-	μC



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